

# **Surface Mount PIN Diodes**

### MA4P1250, MA4P1450 SMQ™

#### **Features**

- Non-Rollable MELF Design
- Hermetically Sealed
- Low Loss, Low Distortion
- Passivated PIN Diode Chips
- Full Face Chip Bonds
- Non-Magnetic Package
- Pick and Place Compatibility



The MA4P1250 and MA4P1450 are square surface mountable PIN diodes in a non-rollable, metal electrode leadless faced (MELF) package. They incorporate passivated PIN diode chips that are full face bonded to refractory metal pins. These parts utilize M/A-COM's HIPAX technology in a low inductance ceramic package with no ribbons or whisker wires. The package is hermetically sealed at temperatures exceeding 300°C.

### **Applications**

The MA4P1250 is designed for use as a low loss switching element from HF through UHF. Its high power rating allows performance in antenna switch elements at RF power levels greater than 100 watts CW. It is designed to meet the low distortion requirements of mobile radios.

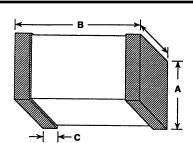
The MA4P1450 is a higher power diode. It has lower distortion at RF CW power greater than 10 watts and can dissipate 7.5 watts.

### **Designed for Automated Assembly**

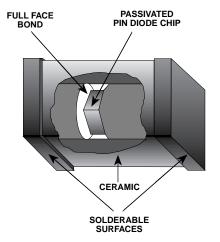
These surface mount PIN diodes are designed for high volume tape and reel assembly. The square package eases automatic pick and place indexing and assembly. The parallel flat surfaces are suitable for key jaw or vacuum pickup techniques. All solderable surfaces are tin plated and compatible with reflow and vapor phase soldering methods.

### **Environmental Capability**

These HIPAX diodes are applicable for use in industrial and military applications. They can meet the environmental requirements of MIL-STD-750 and MIL-STD-202 or be screened to JAN-TX and other high reliability standards.



		Size, Inches (mm)			
Model No.	Case Style	A(sq.) Min./Max.	B Min./Max.	C Min./Max.	
MA4P1250	1072	0.080/0.095 (2.03/2.41)	0.115/0.135 (2.92/3.43)	0.008/0.030	
MA4P1450	1091	0.138/0.155 (3.51/3.94)	0.180/0.200 (4.57/5/08)	(0.203/0.762)	



SMQ is a trademark of M/A-COM, Inc.

Specifications Subject to Change Without Notice.

M/A-COM, Inc. North America:

Tel. (800) 366-2266 Fax (800) 618-8883 Asia/Pacific: Tel. +81 3 3263 8761

Fax +81 3 3263 8769

Europe: Tel. +44 (1344) 869 595 Fax +44 (1344) 300 020

V3.00

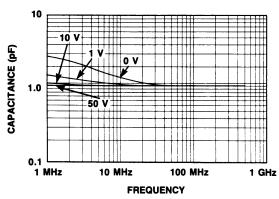
### Electrical Specifications @ 25°C (MA4P1250)

Parameter	Minimum	Typical	Maximum	Unit	Condition
Series Resistance	_	0.5	0.75	Ω	F = 100 MHz I = 50 mA
Capacitance	_	0.9	1.2	pF	F = 1 MHz V = 50 V
Parallel Resistance	5 K	10 K	_	Ω	F = 100 MHz V = 0 V
Carrier Lifetime	2.0	4.0	_	μs	I = 10 mA
Forward Bias Harmonic Distortion (R $\frac{2a}{a}$ , R $\frac{3a}{a}$ )	80	90	_	dBc	F = 100 MHz P = 30W I = 50 mA
Reverse Bias Harmonic Distortion (R2a, R3a)	60	70	dBc		F = 100 MHz P = 0 dBm V = 0 V
Voltage Rating	50			V	Ι = 10 μΑ
Forward Voltage	_	1.0	_	V	I = 50 mA

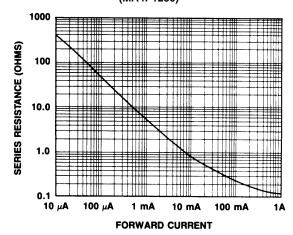
<sup>\*</sup> Available only in case style 1072.

### **Typical Performance Curves**

#### **CAPACITANCE vs FREQUENCY (MA4P1250)**



### SERIES RESISTANCE AT 100 MHZ vs FORWARD CURRENT (MA4P1250)

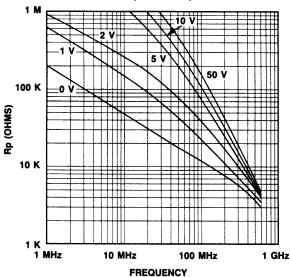


Specifications Subject to Change Without Notice.

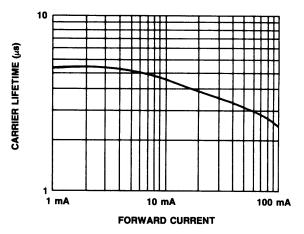
### Absolute Maximum Ratings @ 25°C

Parameter	Absolute Maximum		
Voltage	50 Volts		
Operating Temperature	-65°C to + 175°C		
Storage Temperature	-65°C to +175°C		
Power Dissipation			
Free Air	1.5 Watts		
Contact Surfaces @ +25°C	4.0 Watts		

# CARRIER LIFETIME vs FORWARD CURRENT (MA4P1250)



# PARALLEL RESISTANCE vs FREQUENCY AND REVERSE BIAS (MA4P1250)



M/A-COM, Inc.

Fax +44 (1344) 300 020

■ Europe: Tel. +44 (1344) 869 595

2

Fax +81 3 3263 8769

# MA4P1450 PIN Diodes for High Volume Applications Electrical Specifications @ 25°C

Parameter	Minimum	Typical	Maximum	Unit	Condition
Series Resistance	_	0.5	0.75	Ohms	I <sub>F</sub> = 50 mA F = 100 MHz
Capacitance	_	1.8	2.5	pF	F = 1 MHz $V_R = 0$
Parallel Resistance	5 K	10 K	_	Ø	F = 100 MHz V <sub>R</sub> = 0
Carrier Lifetime	4	6	_	μS	I <sub>F</sub> = 10 mA
Forward Bias Harmonic Distortion (R $\frac{2a}{a}$ , R $\frac{3a}{a}$ )	80	90	_	dBc	F = 100 MHz P = 30W I <sub>F</sub> = 100 mA
Reverse Bias Harmonic Distortion (R $\frac{2a}{a}$ , R $\frac{3a}{a}$ )	60	70	_	dBc	F = 100 MHz P = 0 dBm V = 0 Volts
Voltage Rating	50	_	_	Volts	I <sub>V</sub> = 10 mA
Forward Voltage	1.0	_	_	_	100 mA
Thermal Resistance Junction Case R <sub>TH(I-C)</sub>	_	12.5	15	°C/Watt	_

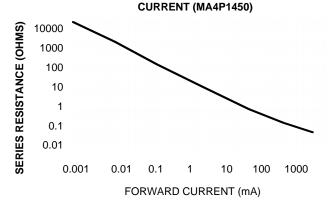
Note: Available only in case style 1091.

### Absolute Maximum Ratings @ 25°C

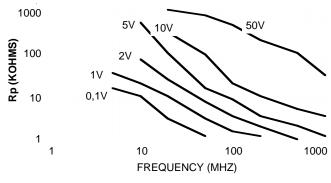
Parameter	Absolute Maximum			
Operating Temperature	-65°C to + 175°C			
Storage Temperature	-65°C to +175°C			
DC Reverse Voltage	50 Volts			
Power Dissipation				
Free Air	1.5 Watts			
Contact Surfaces @ +25°C	4.0 Watts			

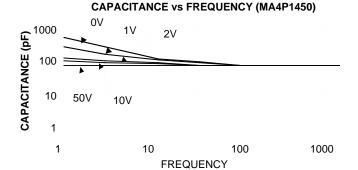
### **Typical Performance Curves**

### SERIES RESISTANCE AT 100 MHZ vs FORWARD



## PARALLEL RESISTANCE vs FREQUENCY AND REVERSE BIAS (MA4P1450)





M/A-COM, Inc.

Specifications Subject to Change Without Notice.

3

North America:

Tel. (800) 366-2266 Fax (800) 618-8883 Asia/Pacific: Tel. +81 3 3263 8761
Fax +81 3 3263 8769

Europe: Tel. +44 (1344) 869 595 Fax +44 (1344) 300 020